

Application Data Sheet

Application Information

Application number::

Filing Date::

Application Type:: Regular

Subject Matter:: Utility

Suggested classification::

Suggested Group Art Unit::

CD-ROM or CD-R??::

Number of CD disks::

Number of copies of CDs::

Sequence Submission::

Computer Readable Form (CRF)?::

Number of copies of CRF::

Title:: INTERNAL VOLTAGE GENERATING CIRCUIT IN
SEMICONDUCTOR MEMORY DEVICE

Attorney Docket Number:: 00939H-088000US

Request for Early Publication:: No

Request for Non-Publication:: No

Suggested Drawing Figure::

Total Drawing Sheets:: 2

Small Entity?:: No

Latin name::

Variety denomination name::

Petition included?:: No

Petition Type::

Licensed US Govt. Agency::

Contract or Grant Numbers One::

Secrecy Order in Parent Appl.: No

Applicant Information

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Korea, South
Status:: Full Capacity
Given Name:: Chang-Ho
Middle Name::
Family Name:: DO
Name Suffix::
City of Residence:: Kyoungki-do
State or Province of Residence::
Country of Residence:: Korea, South
Street of Mailing Address:: San 136-1, Ami-ri, Bubal-eub, Ichon-shi
City of Mailing Address:: Kyoungki-do
State or Province of mailing address::
Country of mailing address:: Korea, South
Postal or Zip Code of mailing address:: 467-860

Correspondence Information

Correspondence Customer Number:: 20350

Representative Information

Representative Customer Number:: 20350

Domestic Priority Information

Application:: Continuity Type:: Parent Application:: Parent Filing Date::

Foreign Priority Information

Country:: Application number:: Filing Date::
Republic of Korea 2003-99597 12/30/2003

Assignee Information

Assignee Name:: Hynix Semiconductor Inc.
Street of mailing address:: San 136-1, Ami-ri, Bubal-eub
City of mailing address:: Ichon-shi
State or Province of mailing address:: Kyoungki-do
Country of mailing address:: Republic of Korea
Postal or Zip Code of mailing address:: 467-860